

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Units |
|-----------------------------------|--------------|------------------------|------------------|-------|-------|
| Drain-Source Voltage | | | V _{DSS} | 30 | V |
| Gate-Source Voltage | | | V _{GSS} | ±12 | V |
| Continuous Drain Current (Note 5) | Steady State | T _A = +25°C | I _D | 220 | mA |
| | | T _A = +85°C | | 150 | |
| Pulsed Drain Current (Note 6) | | | I _{DM} | 500 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Units |
|--------------------------------------------------|--------------|-----------------------------------|-------------|-------|
| Total Power Dissipation (Note 5) | Steady state | P _D | 393 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady state | R _{θJA} | 318 | °C/W |
| Operating and Storage Temperature Range | | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---------------------------------------------------------|---------------------|-----|------|-----|------|-----------------------------------------------------------------------------------------------|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 30 | — | — | V | V _{GS} = 0V, I _D = 250μA |
| Zero Gate Voltage Drain Current @T _C = +25°C | I _{DSS} | — | — | 100 | nA | V _{DS} = 24V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | — | — | ±10 | μA | V _{GS} = ±10V, V _{DS} = 0V |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | 0.4 | — | 1.0 | V | V _{DS} = V _{GS} , I _D = 250μA |
| Static Drain-Source On-Resistance | R _{DS(on)} | — | — | 1.5 | Ω | V _{GS} = 4.5V, I _D = 100mA |
| | | — | — | 2.0 | | V _{GS} = 2.5V, I _D = 50mA |
| | | — | — | 3.0 | | V _{GS} = 1.8V, I _D = 20mA |
| | | — | — | 4.5 | | V _{GS} = 1.5V, I _D = 10mA |
| | | — | 2.8 | — | | V _{GS} = 1.2V, I _D = 1mA |
| Diode Forward Voltage | V _{SD} | — | 0.75 | 1.0 | V | V _{GS} = 0V, I _S = 10mA |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | |
| Input Capacitance | C _{iss} | — | 22.2 | — | pF | V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz |
| Output Capacitance | C _{oss} | — | 2.9 | — | pF | |
| Reverse Transfer Capacitance | C _{rss} | — | 2.2 | — | pF | |
| Total Gate Charge | Q _g | — | 0.35 | — | nC | V _{GS} = 4.5V, V _{DS} = 15V, I _D = 200mA |
| Gate-Source Charge | Q _{gs} | — | 0.05 | — | nC | |
| Gate-Drain Charge | Q _{gd} | — | 0.02 | — | nC | |
| Turn-On Delay Time | t _{D(on)} | — | 3.1 | — | ns | V _{DD} = 10V, V _{GS} = 4.5V, R _G = 6Ω, I _D = 200mA |
| Turn-On Rise Time | t _r | — | 2.0 | — | ns | |
| Turn-Off Delay Time | t _{D(off)} | — | 20 | — | ns | |
| Turn-Off Fall Time | t _f | — | 6.9 | — | ns | |

- Notes:
- Device mounted on FR-4 PCB, with minimum recommended pad layout.
 - Device mounted on minimum recommended pad layout test board, 10μs pulse duty cycle = 1%.
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to product testing.

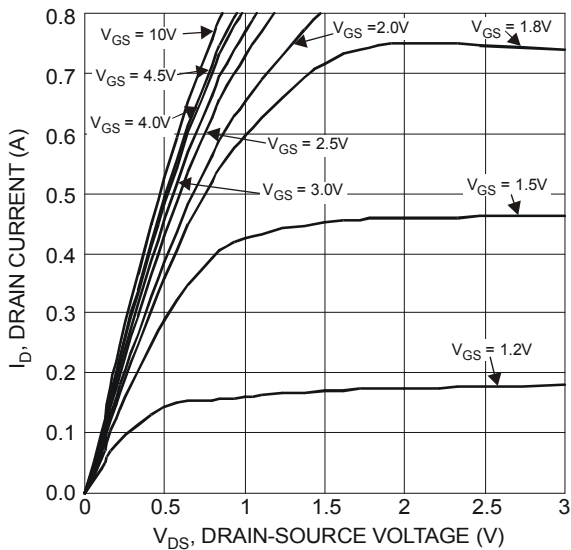


Figure 1 Typical Output Characteristics

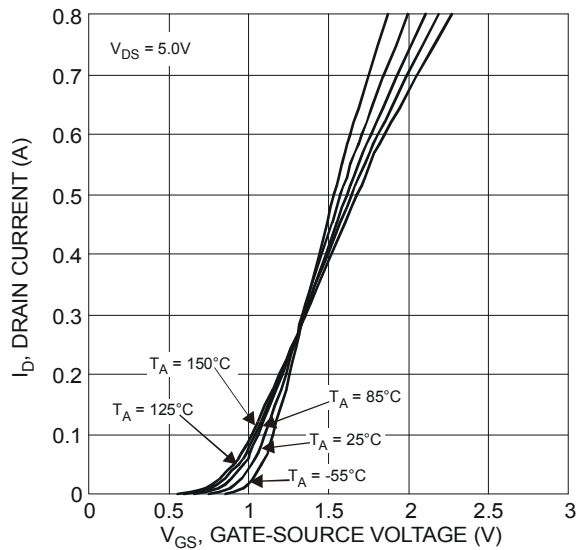


Figure 2 Typical Transfer Characteristics

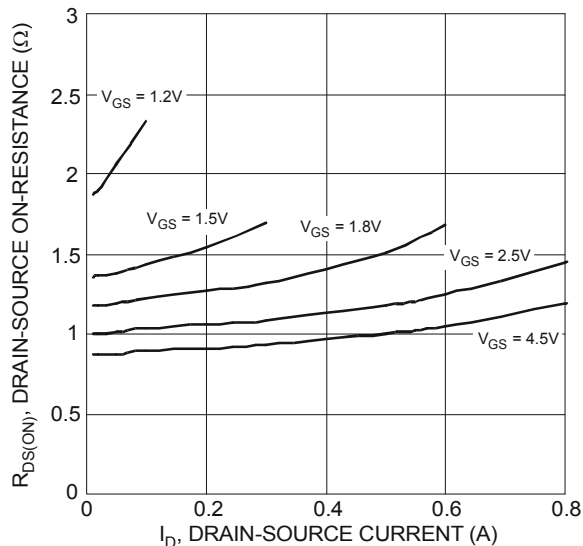


Figure 3 Typical On-Resistance vs. Drain Current and Gate Voltage

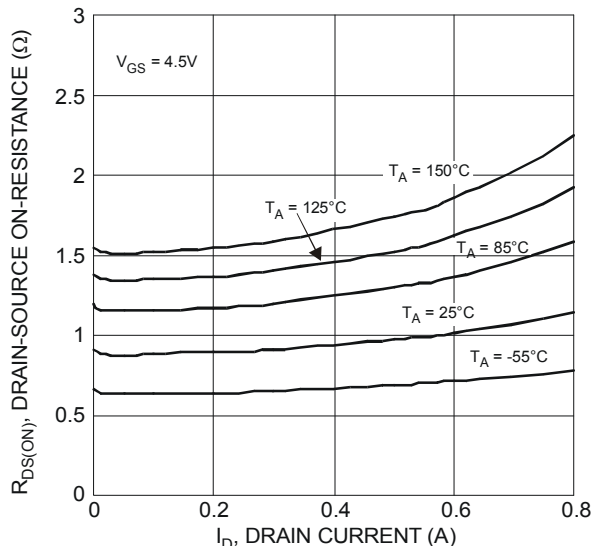


Figure 4 Typical On-Resistance vs. Drain Current and Temperature

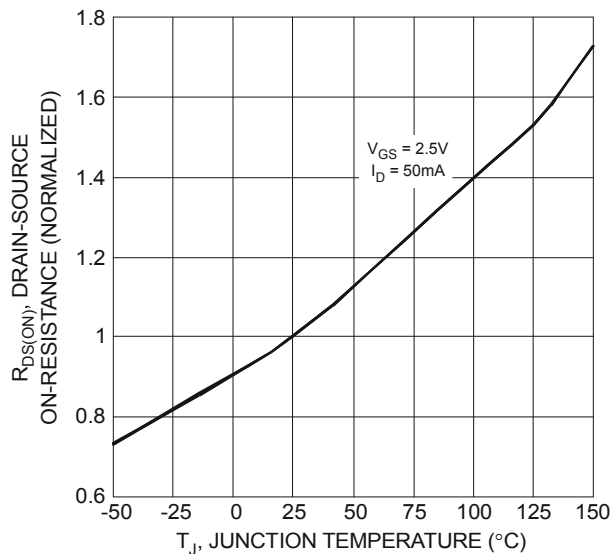


Figure 5 On-Resistance Variation with Temperature

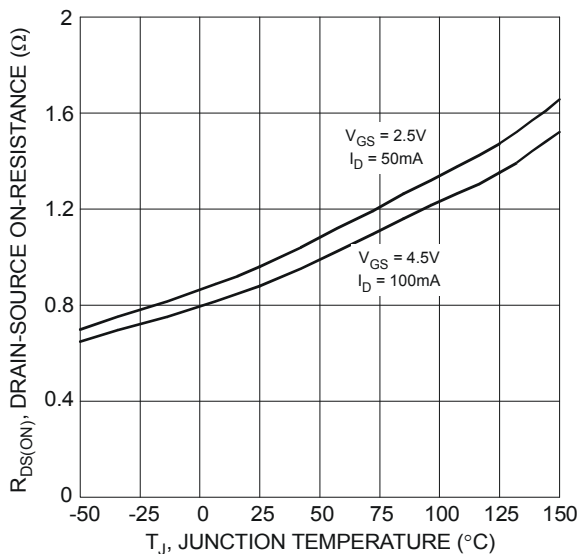


Figure 6 On-Resistance Variation with Temperature

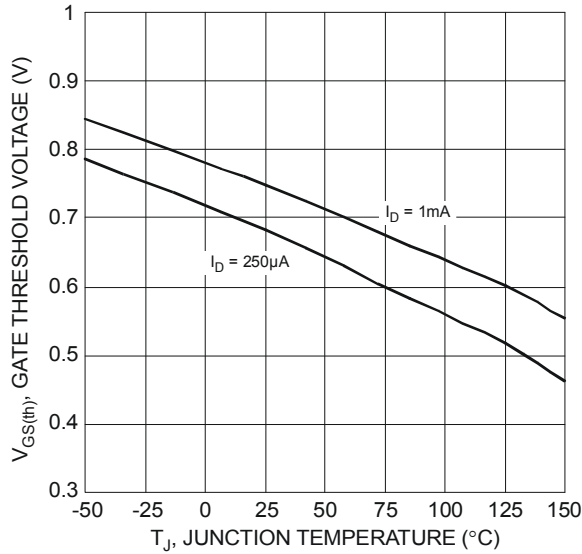


Figure 7 Gate Threshold Variation vs. Ambient Temperature

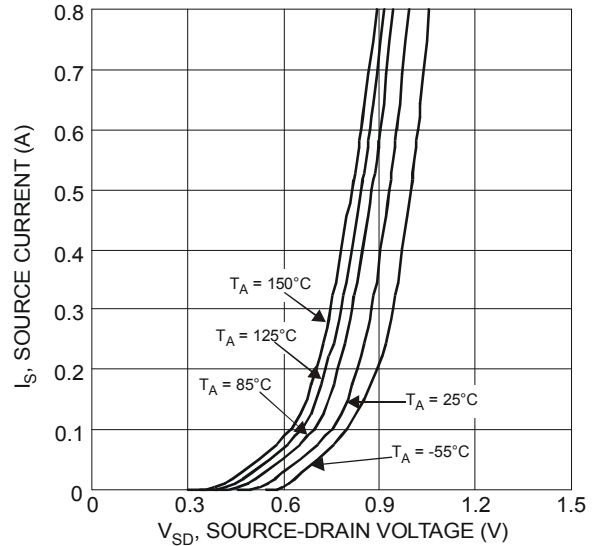


Figure 8 Diode Forward Voltage vs. Current

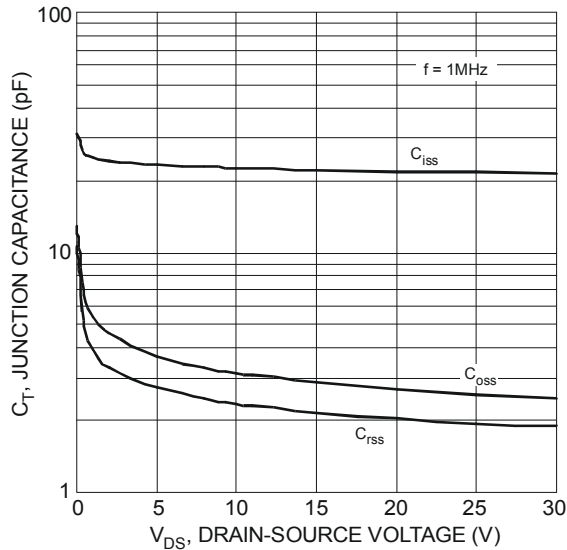


Figure 9 Typical Junction Capacitance

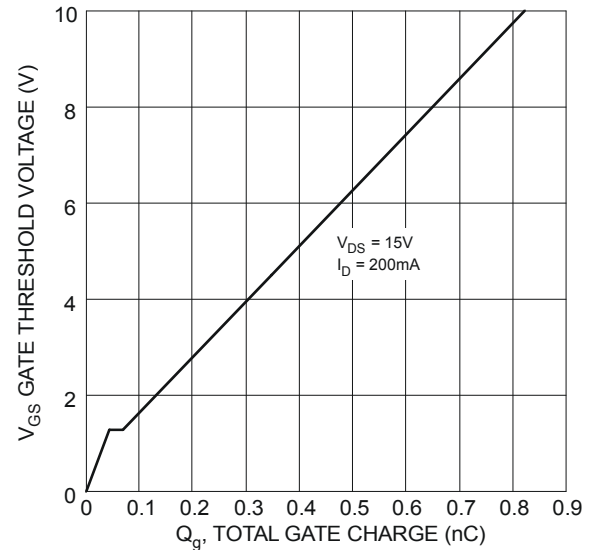


Figure 10 Gate Charge

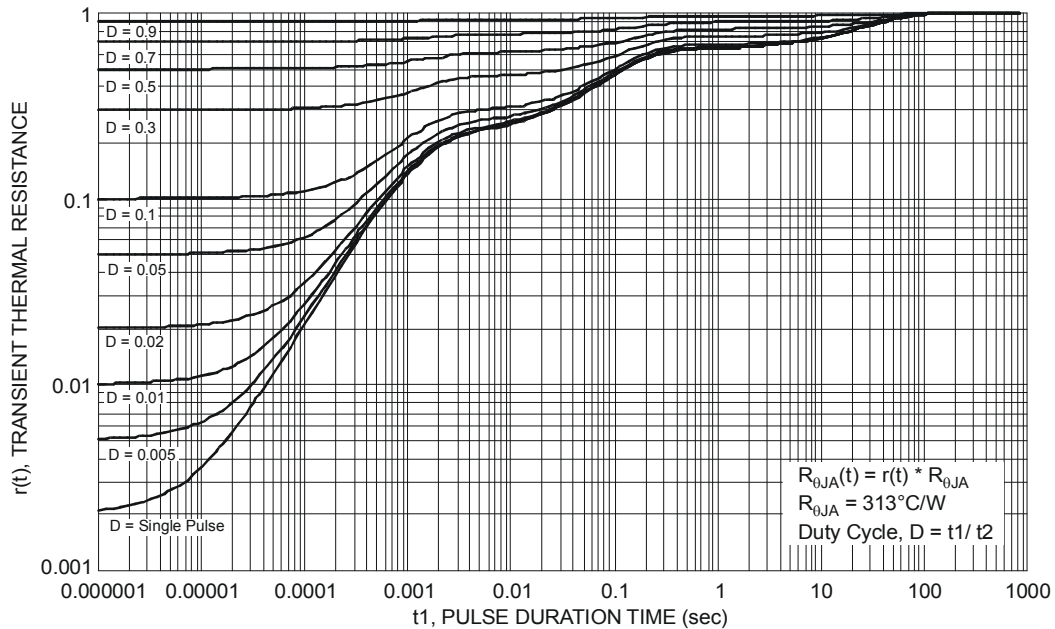
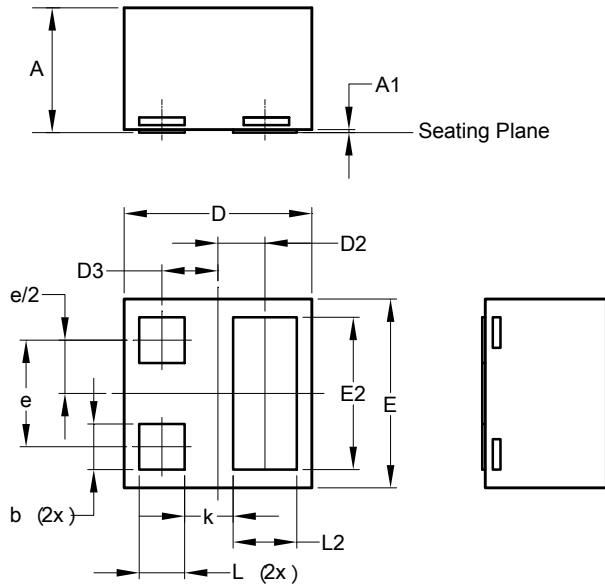


Figure 11 Transient Thermal Resistance

Package Outline Dimensions

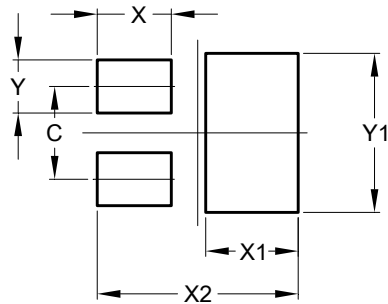
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



| X2-DFN0606-3 | | | |
|----------------------|-----------|------|------|
| Dim | Min | Max | Typ |
| A | 0.36 | 0.42 | 0.39 |
| A1 | 0 | 0.05 | 0.02 |
| b | 0.10 | 0.20 | 0.15 |
| D | 0.57 | 0.67 | 0.62 |
| D2 | 0.155 BSC | | |
| D3 | 0.185 BSC | | |
| E | 0.57 | 0.67 | 0.62 |
| E2 | 0.40 | 0.60 | 0.50 |
| e | 0.35 BSC | | |
| k | 0.16 REF | | |
| L | 0.09 | 0.21 | 0.15 |
| L2 | 0.11 | 0.31 | 0.21 |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 0.350 |
| X | 0.280 |
| X1 | 0.350 |
| X2 | 0.760 |
| Y | 0.200 |
| Y1 | 0.600 |

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